

SURFACE MOUNT PHEMT 2 WATT POWER AMPLIFIER, 9 - 12 GHz

Typical Applications

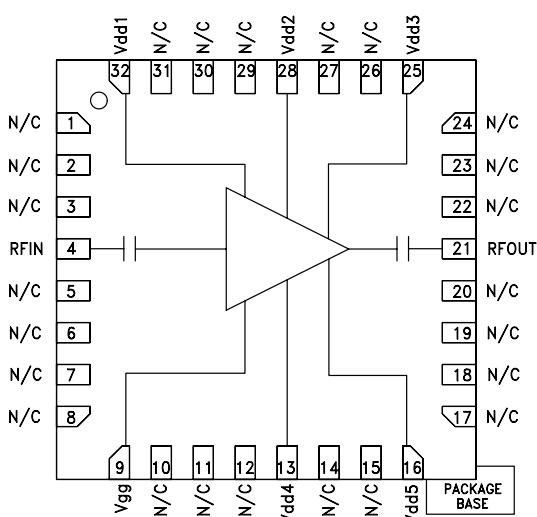
The HMC487LP5E is ideal for use as a power amplifier for:

- Point-to-Point Radios
- Point-to-Multi-Point Radios
- Test Equipment and Sensors
- Military End-Use

Features

Saturated Power: +33 dBm @ 20% PAE
 Output IP3: +36 dBm
 Gain: 20 dB
 +7V @ 1300 mA Supply
 50 Ohm Matched Input/Output
 25 mm² Leadless SMT Package

Functional Diagram



General Description

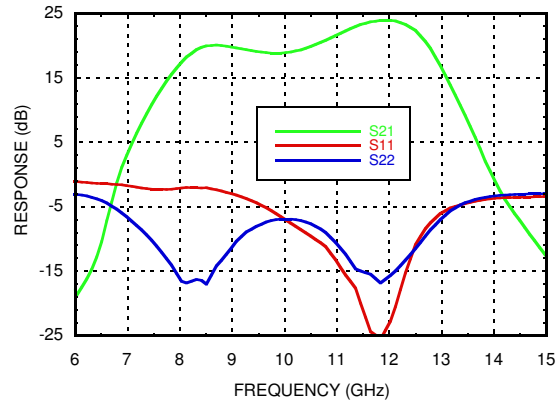
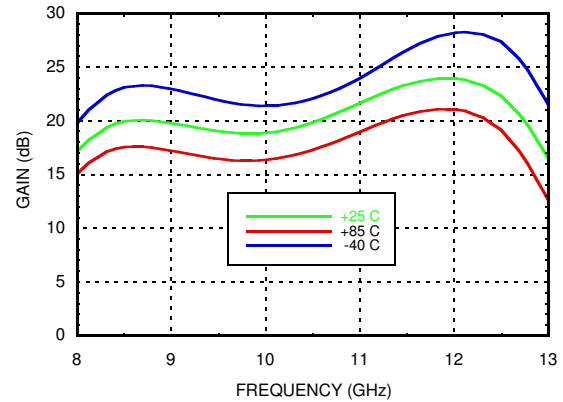
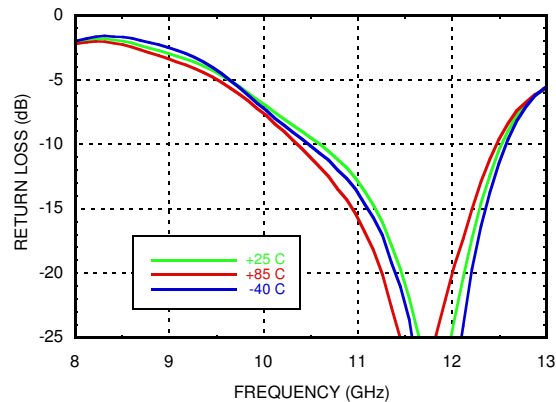
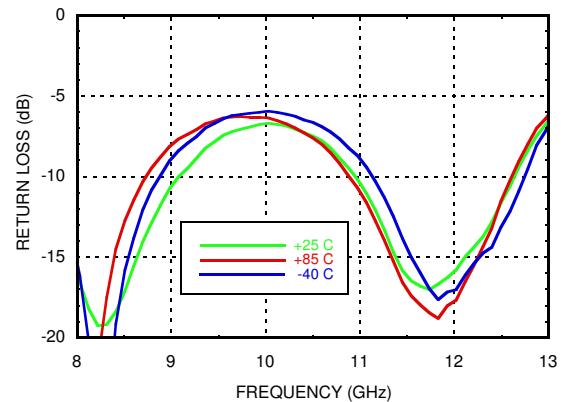
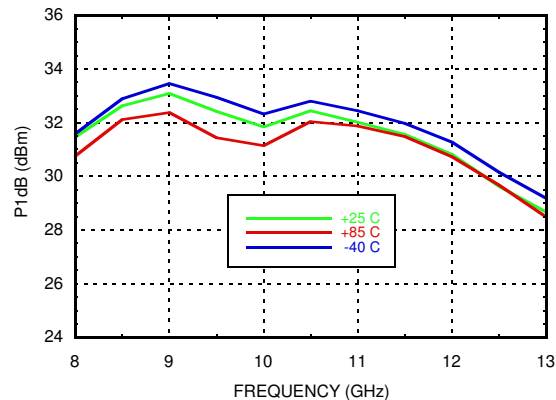
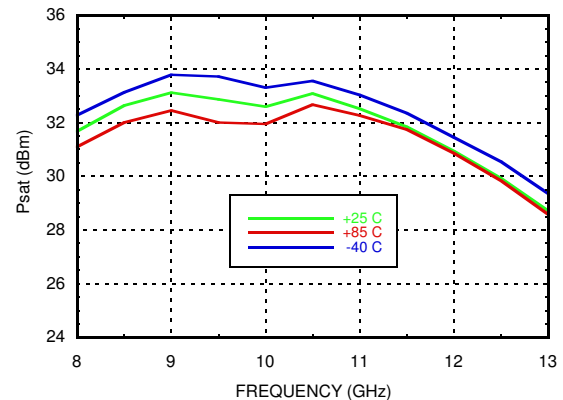
The HMC487LP5E is a high dynamic range GaAs PHEMT MMIC 2 Watt Power Amplifiers housed in leadless 5 x 5 mm surface mount packages. Operating from 9 to 12 GHz, the amplifier provides 20 dB of gain, +33 dBm of saturated power and 20% PAE from a +7V supply voltage. Output IP3 is +36 dBm typical. The RF I/Os are DC blocked and matched to 50 Ohms for ease of use. The HMC487LP5E eliminates the need for wire bonding, allowing use of surface mount manufacturing techniques.

Electrical Specifications, $T_A = +25^\circ\text{C}$, $V_{dd1, 2, 3, 4, 5} = +7\text{V}$, $I_{dd} = 1300\text{ mA}^*$

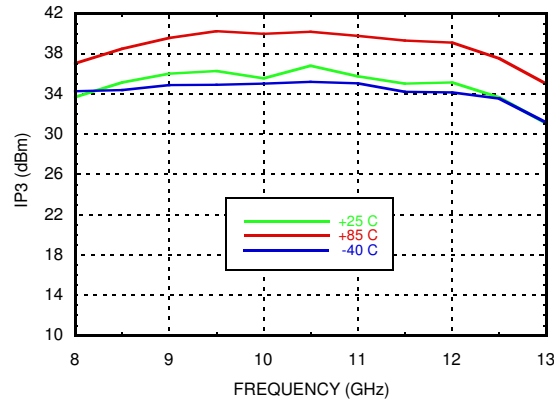
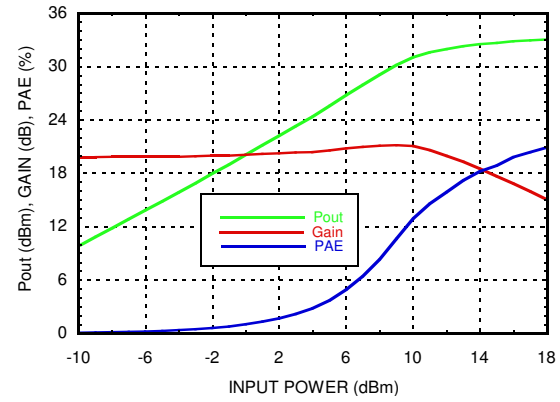
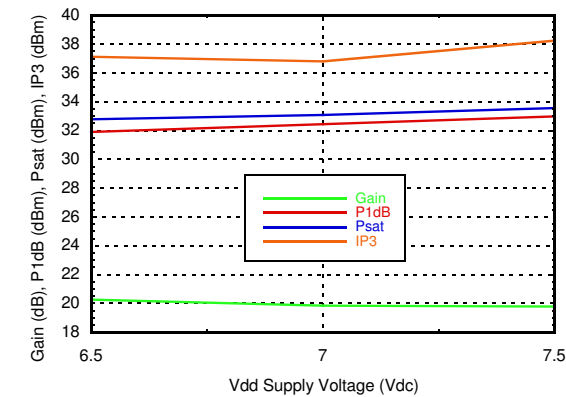
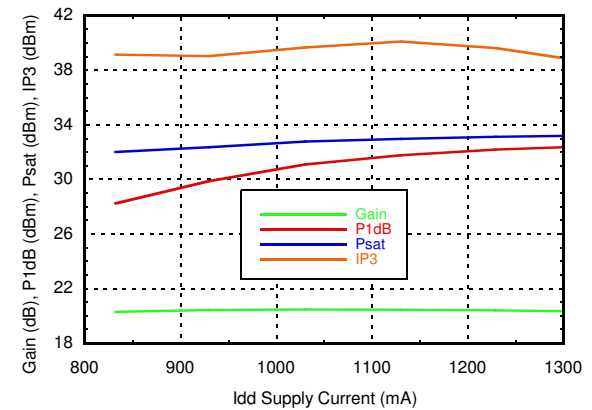
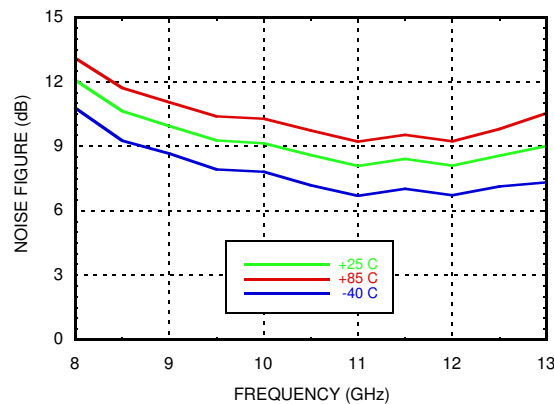
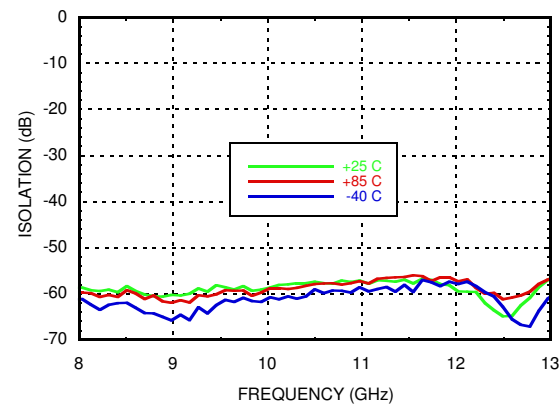
Parameter	Min.	Typ.	Max.	Min.	Typ.	Max.	Units
Frequency Range	9 - 11			11 - 12			GHz
Gain	17	20		19	22		dB
Gain Variation Over Temperature		0.05	0.07		0.05	0.07	dB/°C
Input Return Loss		7			15		dB
Output Return Loss		7			15		dB
Output Power for 1 dB Compression (P1dB)	29	32		28	31		dBm
Saturated Output Power (Psat)		33			32		dBm
Output Third Order Intercept (IP3)		36			35		dBm
Noise Figure		9			8		dB
Supply Current (Idd)(Vdd = +7V, Vgg = -0.3V Typ.)		1300			1300		mA

* Adjust Vgg between -2 to 0V to achieve Idd = 1300 mA typical.

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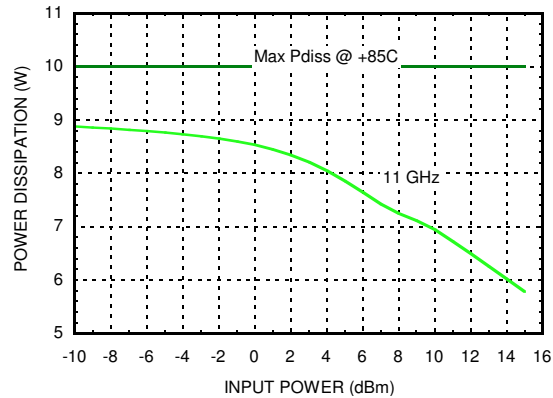
Broadband Gain and Return Loss

Gain vs. Temperature

Input Return Loss vs. Temperature

Output Return Loss vs. Temperature

P1dB vs. Temperature

Psat vs. Temperature


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Output IP3 vs. Temperature

Power Compression @ 10.5 GHz

**Gain Power and OIP3
vs. Supply Voltage @10.5 GHz**

**Gain, Power and OIP3
vs. Supply Current @ 10.5 GHz**

Noise Figure vs. Temperature

Reverse Isolation vs. Temperature


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Power Dissipation*

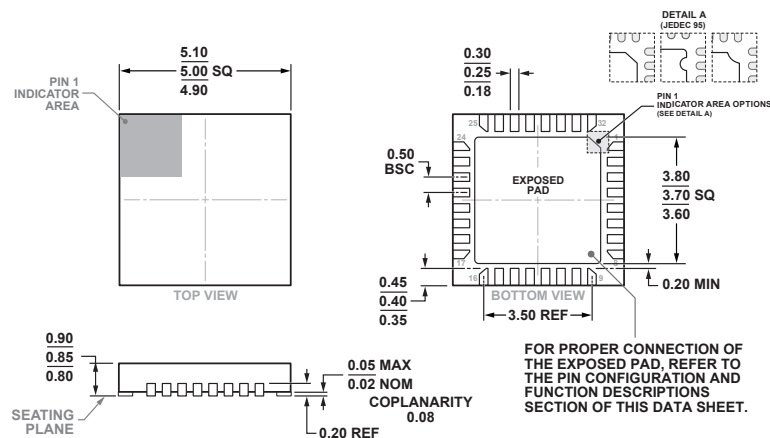


* Refer to "Thermal Management for Surface Mount Components" application note herein.



**ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS**

Outline Drawing



COMPLIANT TO JEDEC STANDARDS MO-220-VHHD-4

32-Lead Lead Frame Chip Scale Package [LFCSP]
5 mm x 5 mm Body and 0.85 mm Package Height
(HCP-32-1)

Dimensions shown in millimeters

Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking ^[2]
HMC487LP5ETR	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL3 ^[1]	H487 XXXX
HMC487LP5E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL3 ^[1]	H487 XXXX

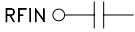
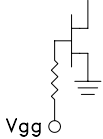
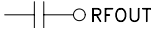
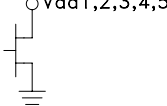
[1] Max peak reflow temperature of 260 °C

[2] 4-Digit lot number XXXX

For price, delivery, and to place orders: Analog Devices, Inc., One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106
Phone: 781-329-4700 • Order online at www.analog.com
Application Support: Phone: 1-800-ANALOG-D

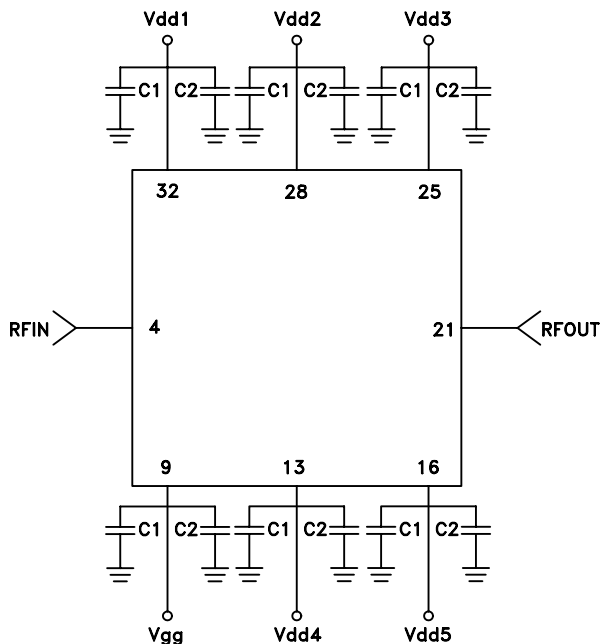
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Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1 - 3, 5 - 8, 10 - 12, 14, 15, 17 - 20, 22 - 24, 26, 27, 29 - 31	N/C	No connection required. These pins may be connected to RF/DC ground without affecting performance.	
4	RFIN	This pin is AC coupled and matched to 50 Ohms.	
9	Vgg	Gate control for amplifier. Adjust to achieve I _{dd} of 1300 mA. Please follow "MMIC Amplifier Biasing Procedure" Application Note. External bypass capacitors of 100 pF and 2.2 μF are required.	
21	RFOUT	This pin is AC coupled and matched to 50 Ohms.	
32, 28, 25, 13, 16	Vdd1, Vdd2, Vdd3, Vdd4, Vdd5	Power Supply Voltage for the amplifier. External bypass capacitors of 100 pF and 2.2 μF are required.	
	GND	Ground: Backside of package has exposed metal ground slug that must be connected to ground through a short path. Vias under the device are required	

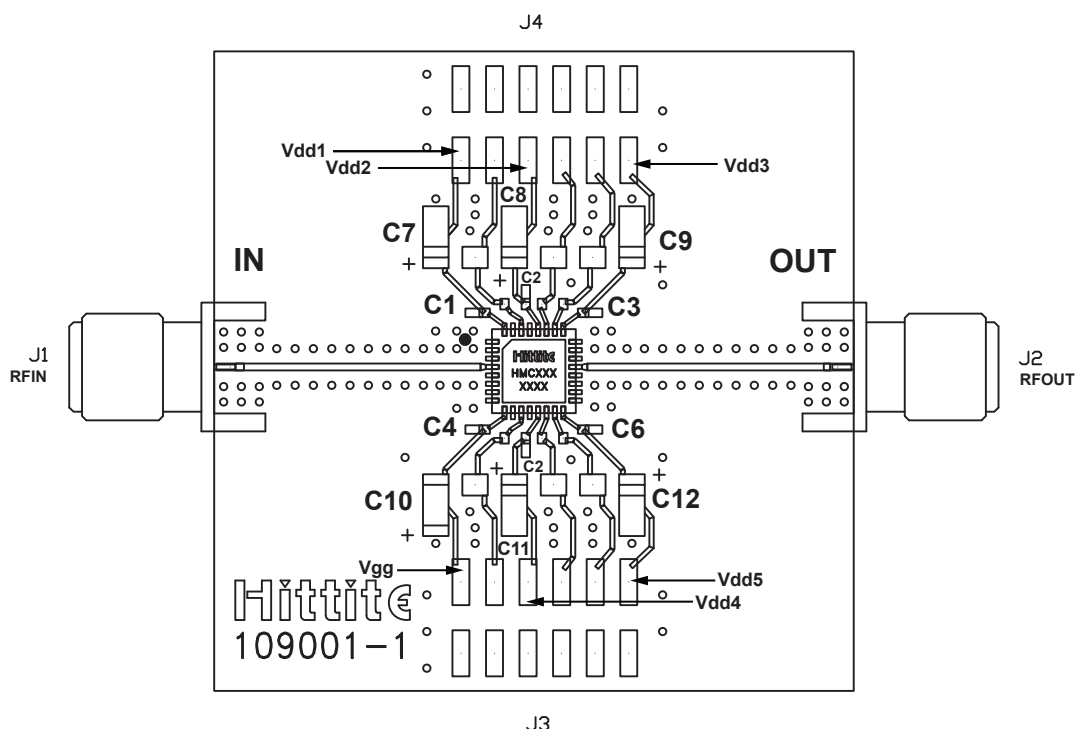
Application Circuit

Component	Value
C1	100 pF
C2	2.2 μF



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Evaluation PCB



List of Materials for Evaluation PCB 108190 ^[1]

Item	Description
J1, J2	SRI PC Mount SMA Connector
J3, J4	2mm DC Header
C1 - C6	100 pF capacitor, 0402 pkg.
C7 - C12	2.2μF Capacitor, Tantalum
U1	HMC487LP5E Amplifier
PCB ^[2]	109001 Evaluation PCB

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350.

The circuit board used in this application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. Copper filled vias under the device are recommended. The evaluation board should be mounted to an appropriate heat sink. The evaluation circuit board shown is available from Analog Devices upon request.